

SOD-923 ESD 静电保护二极管

■Features 特点

Un-directional ESD Protection 单通道单向静电保护

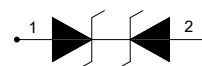
■Applications 应用

Notebooks, desktops, and servers 笔记本、台式机和服务器

Cellular handsets and accessories 蜂窝手机及配件

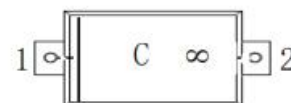
Personal Digital Assistants 个人数码助手

Peripherals 电脑外设



■Internal Schematic Diagram 内部结构

■Device Marking 产品打标



■Absolute Maximum Ratings 最大额定值

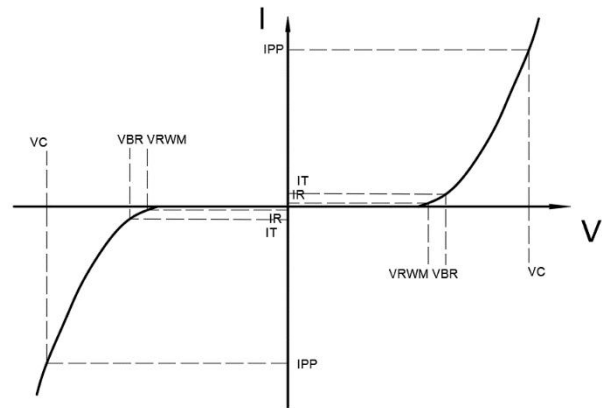
Characteristic 特性参数	Symbol 符号	Rat 额定值	Unit 单位
ESD (IEC61000-4-2 contact discharge) @25°C接触放电	V_{ESD}	± 20	KV
ESD (IEC61000-4-2 air discharge) @25°C空气放电	V_{ESD}	± 20	KV
Peak Pulse Power @25°C峰值脉冲功率	P_{PK}	68	W
Peak Pulse Current @25°C峰值脉冲电流	I_{PP}	5.5	A
Lead Temperature 管脚温度	T_L	260	°C
Lead Solder Time 管脚焊接时间	T_L	10	S
Operating Temperature 工作温度	T_{op}	-40~85	°C
Junction Temperature 结温	T_J	-55~125	°C
Storage Temperature 储存温度	T_{stg}	-55~150	°C

■ Electrical Characteristics 电特性

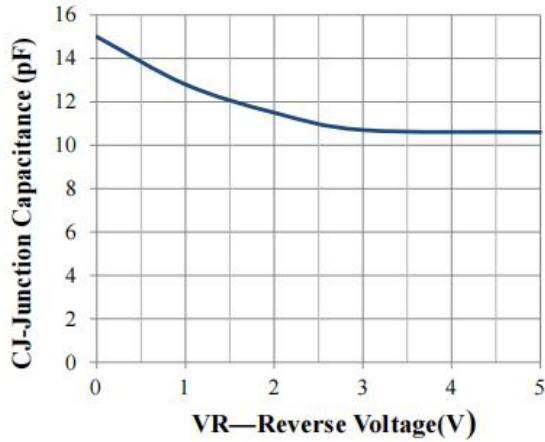
($T_A=25^{\circ}\text{C}$ unless otherwise noted 如无特殊说明, 温度为 25°C)

Characteristic Parameters 特性参数	Symbol 符号	Min 最小值	Typ 典型值	Max 最大值	Unit 单位	Condition 条件
Reverse Stand-off Voltage 反向工作电压	V_{RWM}			5	V	
Reverse Breakdown Voltage 反向击穿电压	V_{BR}	5.7		9	V	$I_{\text{T}}=1\text{mA}$
Reverse Leakage Current 反向漏电流	I_{R}			0.1	μA	$V_{\text{RWM}}=5\text{V}$
Clamping Voltage 钳位电压	V_{C}			12	V	$I_{\text{PP}}=1\text{A}, t_{\text{p}}=8/20\mu\text{s}$
Clamping Voltage 钳位电压	V_{C}			17	V	$I_{\text{PP}}=5.5\text{A}, t_{\text{p}}=8/20\mu\text{s}$
Diode Capacitance 二极管电容	C_{D}	8	8.9	15	pF	$V_{\text{R}}=0\text{V}, f=1\text{MHz}$

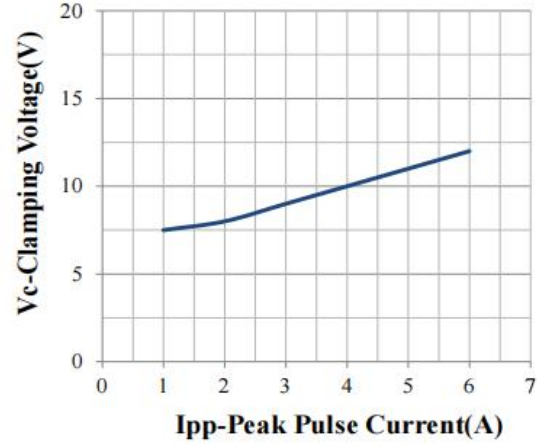
V_{RWM}	Reverse Working Voltage 反向工作电压
$V_{\text{R(BR)}}$	Reverse Breakdown Voltage 反向击穿电压@ $I_{\text{T}}=1\text{mA}$
I_{T}	Test Current 测试电流
I_{R}	Reverse Leakage Current 反向漏电流@ V_{RWM}
V_{C}	Clamping Voltage 钳位电压
I_{PP}	Reverse Peak Pulse Current 浪涌电流
C_{D}	Diode Capacitance 结电容 $V_{\text{IO}}=0\text{V}, f=1\text{MHz}$



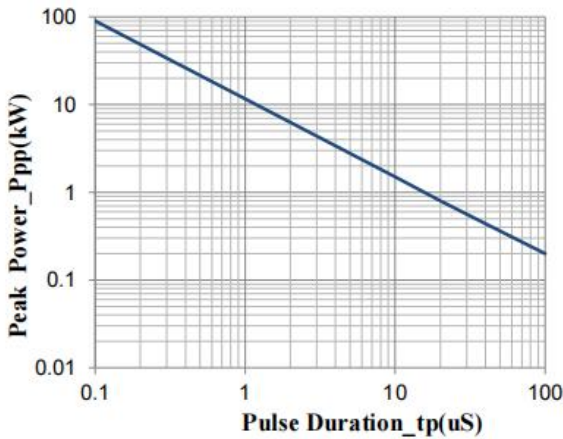
■ Typical Characteristic Curve 典型特性曲线



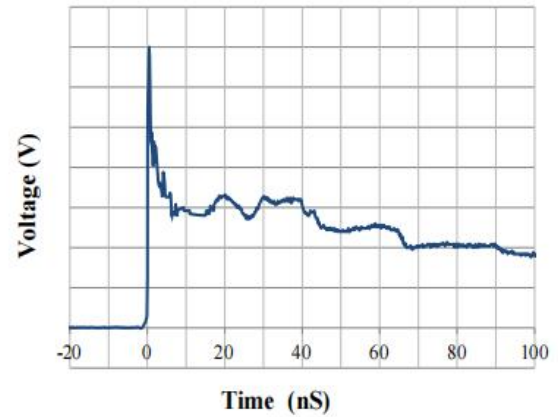
Junction Capacitance vs. Reverse Voltage



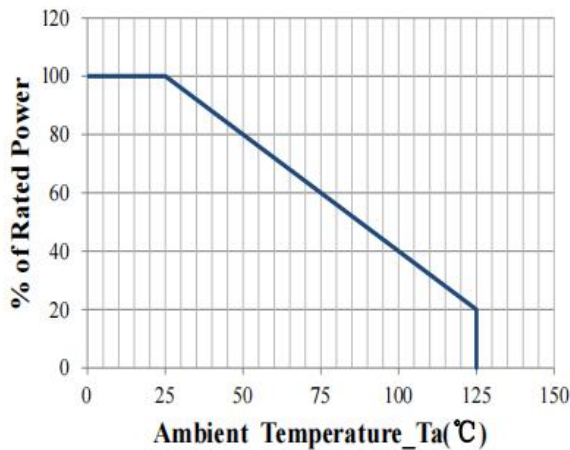
Clamping Voltage vs. Peak Pulse Current



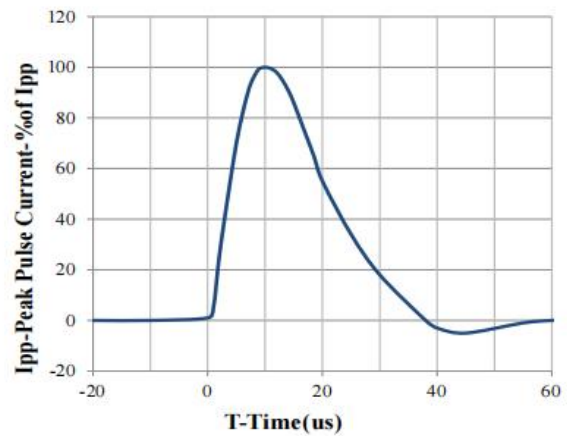
Peak Pulse Power vs. Pulse Time



IEC61000-4-2 Pulse Waveform

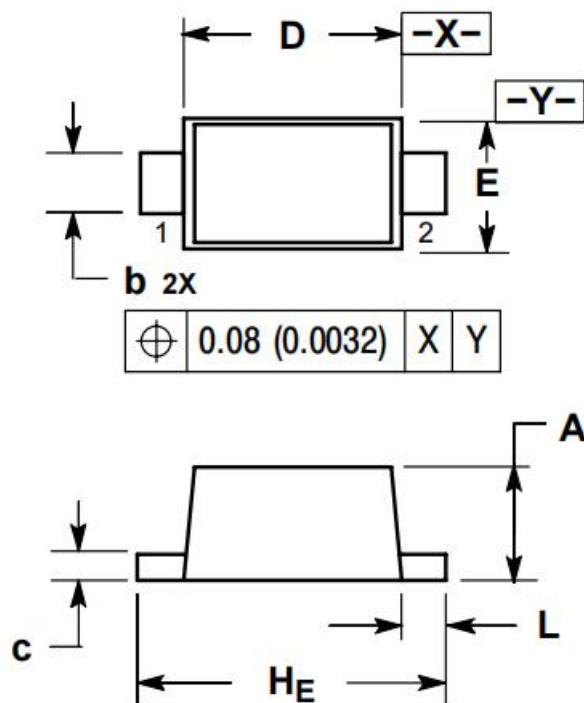


Power Derating Curve



8 X 20us Pulse Waveform

■ Dimension 外形封装尺寸



DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.34	0.37	0.40	0.013	0.015	0.016
b	0.15	0.20	0.25	0.006	0.008	0.010
c	0.07	0.12	0.17	0.003	0.005	0.007
D	0.75	0.80	0.85	0.030	0.031	0.033
E	0.55	0.60	0.65	0.022	0.024	0.026
H_E	0.95	1.00	1.05	0.037	0.039	0.041
L	0.05	0.10	0.15	0.002	0.004	0.006